NSN 5962-00-098-8741

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View Online at https://aerobasegroup.com/nsn/5962-00-098-8741

Body Length:
Between 0.250 inches and 0.260 inches
Body Width:
Between 0.140 inches and 0.150 inches
Body Height:
Between 0.035 inches and 0.050 inches
Maximum Power Dissipation Rating:
400.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and medium power and medium speed and w/enable
Inclosure Material:
Glass and metal
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
8 input
Case Outline Source And Designator:
T0-84 joint electron device engineering council
Terminal Surface Treatment:
Gold
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
27.00 nanoseconds propagation delay time, low to high level output and 32.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Special Features:
Insulator furnished
Precious Material And Location:

Precious Material:

Terminals gold and body gold

Gold

Test Data Document:

26512-123scpe5102 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

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Ferminal Type A	and Q	uantity:
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14 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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